

20V P-Channel Enhancement Mode MOSFET

Voltage

-20 V

Current

420mA

Features

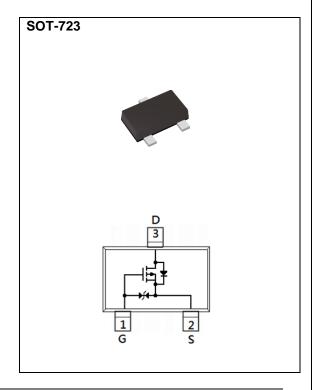
- Advanced Trench Process Technology
- ESD Protected
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case : SOT-723 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0001 ounce, 0.0013 gram



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-20	· v	
Gate-Source Voltage		V _{GS}	±8		
Continuous Drain Current(Note 4)		I _D	420		
Pulsed Drain Current ^(Note 1)		I _{DM} 1000		mA	
Power Dissipation	T _A =25°C		150	mW	
	Derate above 25°C	Pb	1.2	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient ^(Note 5)		R ₀ JA	833	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-0.3	-0.64	-1.0	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-300mA	-	420	600	mΩ	
		V _{GS} =-2.5V, I _D =-200mA	-	540	850		
		V _{GS} =-1.8V, I _D =-100mA	-	685	1200		
		V _{GS} =-1.5V, I _D =-50mA	-	855	1600		
		V _{GS} =-1.2V, I _D =-20mA	-	1540	3000		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V	-	-	±10		
Dynamic ^(Note 6)							
Total Gate Charge	Qg	V _{DS} =-16V, I _D =-300mA,	-	1.2	-	nC	
Gate-Source Charge	Qgs		-	0.1	-		
Gate-Drain Charge	Q_{gd}	VGS=-4.5 V(10.00 2,0)	-	0.2	-		
Input Capacitance	Ciss		-	57.5	-		
Output Capacitance	Coss	V_{DS} =-10V, V_{GS} =0V, f =1MHZ	-	14.2	-	pF	
Reverse Transfer Capacitance	Crss	I=IIVIMZ	-	0.18	-		
Gate resistance	Rg	f=1.0MHZ	-	3.7	-	Ω	
Turn-On Delay Time	td _(on)		-	6	-		
Turn-On Rise Time	tr	V _{DS} =-16V, I _D =-300mA,	-	23	-	ns	
Turn-Off Delay Time	td _(off)	V_{GS} =-4.5V, R _G =3.3 Ω	-	1576	-		
Turn-Off Fall Time	tf		-	752	-		
Drain-Source Diode							
Diode Forward Current	Is		-	-	-180	mA	
Diode Forward Voltage	V _{SD}	Is=-300mA,V _{GS} =0V	-	-0.85	-1	V	

Notes:

- 1.Pulse width<300us, Duty cycle<2%.
- $2. Essentially \ independent \ of \ operating \ temperature \ typical \ characteristics.$
- $3. Repetitive\ rating,\ pulse\ width\ limited\ by\ junction\ temperature\ T_J(MAX) = 150^{\circ}C. Ratings\ are\ based\ on\ low\ frequency\ and\ duty\ cycles\ to\ keep\ initial\ T_J=25^{\circ}C.$
- 4. The maximum current rating is package limited.
- 5.ReJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

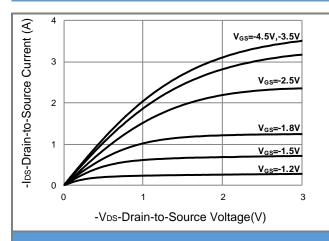


Fig.1 Output Characteristics

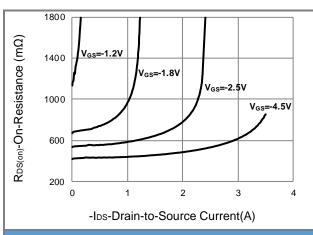


Fig.3 On-Resistance vs. Drain Current

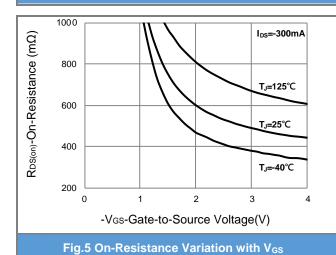


Fig.2 Transfer Characteristics

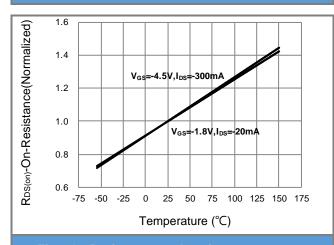


Fig.4 On-Resistance vs. Junction temperature

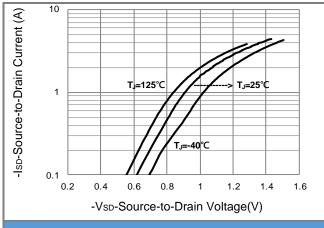


Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

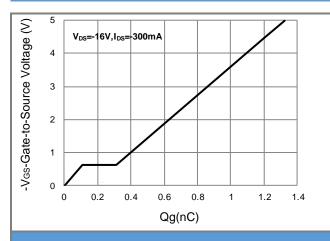


Fig.7 Gate-Charge Characteristics

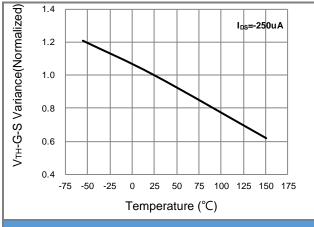


Fig.9 Threshold Voltage Variation with Temperature

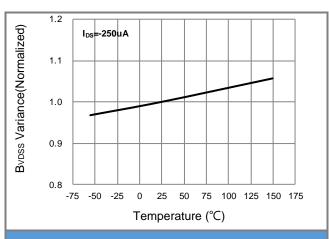


Fig.8 Breakdown Voltage Variation vs. Temperature

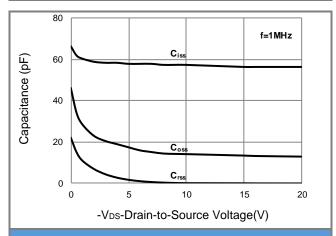


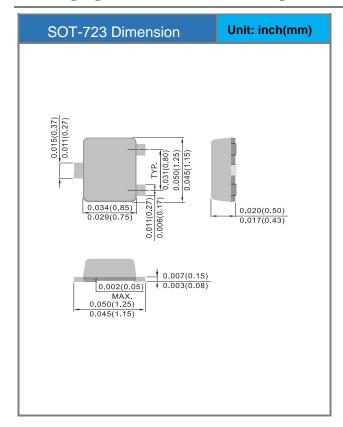
Fig.10 Capacitance vs. Drain-Source Voltage

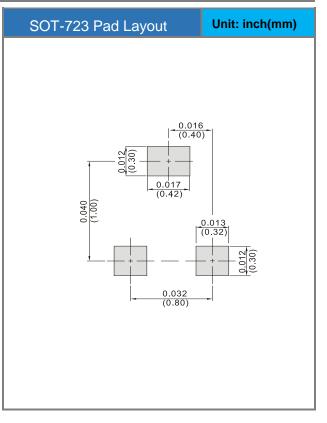


Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJV1717	SOT-723	8K pcs / 7" reel	17

Packaging Information & Mounting Pad Layout





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